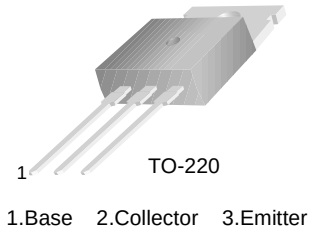


BDX34/A/B/C

Power Linear and Switching Applications

- High Gain General Purpose
- Power Darlington TR
- Complement to BDX33/33A/33B/33C respectively



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage		
	: BDX34	- 45	V
	: BDX34A	- 60	V
	: BDX34B	- 80	V
	: BDX34C	- 100	V
V_{CEO}	Collector-Emitter Voltage		
	: BDX34	- 45	V
	: BDX34A	- 60	V
	: BDX34B	- 80	V
	: BDX34C	- 100	V
I_C	Collector Current (DC)	- 10	A
I_{CP}	*Collector Current (Pulse)	- 15	A
I_B	Base Current	- 0.25	A
P_C	Collector Dissipation ($T_C=25^\circ\text{C}$)	70	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	- 65 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$V_{CEO(sus)}$	* Collector-Emitter Sustaining Voltage : BDX34 : BDX34A : BDX34B : BDX34C	$I_C = -100\text{mA}, I_B = 0$	- 45 - 60 - 80 - 100			V V V V
$V_{CER(sus)}$	* Collector-Emitter Sustaining Voltage : BDX34 : BDX34A : BDX34B : BDX34C	$I_C = -100\text{mA}, I_B = 0$ $R_{BE} = 100\Omega$	- 45 - 60 - 80 - 100			V V V V
$V_{CEV(sus)}$	* Collector-Emitter Sustaining Voltage : BDX34 : BDX34A : BDX34B : BDX34C	$I_C = -100\text{mA}, I_B = 0$ $V_{BE} = -1.5\text{V}$	- 45 - 60 - 80 - 100			V V V V
I_{CBO}	Collector Cut-off Current : BDX34 : BDX34A : BDX34B : BDX34C	$V_{CB} = -45\text{V}, I_E = 0$ $V_{CB} = -60\text{V}, I_E = 0$ $V_{CB} = -80\text{V}, I_E = 0$ $V_{CB} = -100\text{V}, I_E = 0$			- 0.2 - 0.2 - 0.2 - 0.2	mA mA mA mA
I_{CEO}	Collector Cut-off Current : BDX34 : BDX34A : BDX34B : BDX34C	$V_{CE} = -22\text{V}, I_B = 0$ $V_{CE} = -30\text{V}, I_B = 0$ $V_{CE} = -40\text{V}, I_B = 0$ $V_{CE} = -50\text{V}, I_B = 0$			- 0.5 - 0.5 - 0.5 - 0.5	mA mA mA mA
I_{EBO}	Emitter Cut-off Current	$V_{EB} = -5\text{V}, I_C = 0$			- 5	mA
h_{FE}	* DC Current Gain : BDX34/34A : BDX34B/34C	$V_{CE} = -3\text{V}, I_C = -4\text{A}$ $V_{CE} = -3\text{V}, I_C = -3\text{A}$	750 750			
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage : BDX34/34A : BDX34B/34C	$I_C = -4\text{A}, I_B = -8\text{mA}$ $I_C = -3\text{A}, I_B = -6\text{mA}$			- 2.5 - 2.5	V V
$V_{BE(on)}$	* Base-Emitter ON Voltage : BDX34/34A : BDX34B/34C	$V_{CE} = -3\text{V}, I_C = -4\text{A}$ $V_{CE} = -3\text{V}, I_C = -3\text{A}$			- 2.5 - 2.5	V V
V_F	* Parallel Diode Forward Voltage	$I_F = -8\text{A}$			- 4	V

* Pulse Test: PW=300 μ s, duty Cycle =1.5% Pulsed

Typical Characteristics

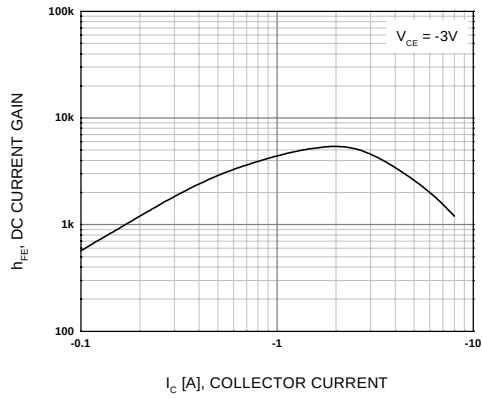


Figure 1. DC Current Gain

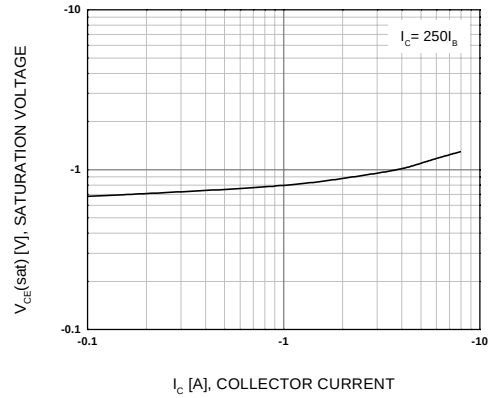


Figure 2. Collector-Emitter Saturation Voltage

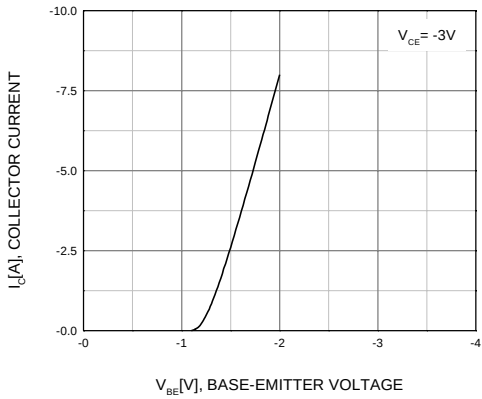


Figure 3. Base-Emitter On Voltage

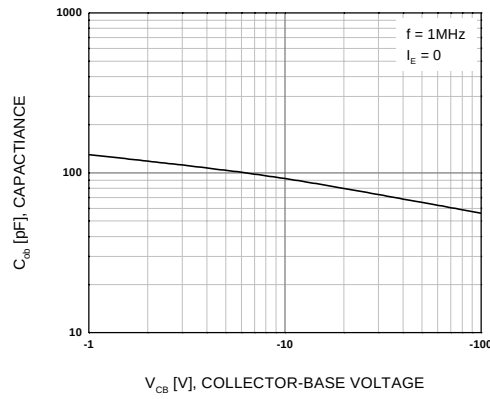


Figure 4. Output Capacitance

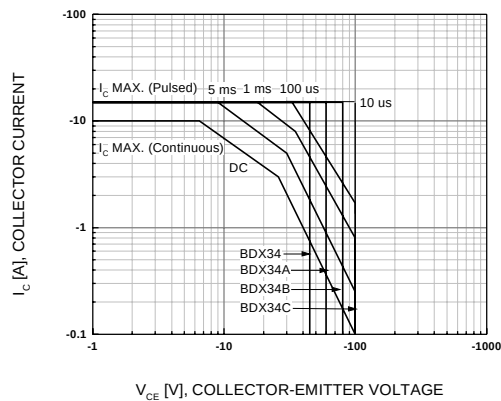


Figure 5. Safe Operating Area

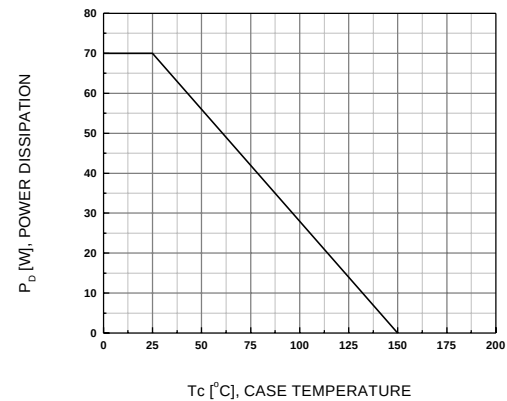
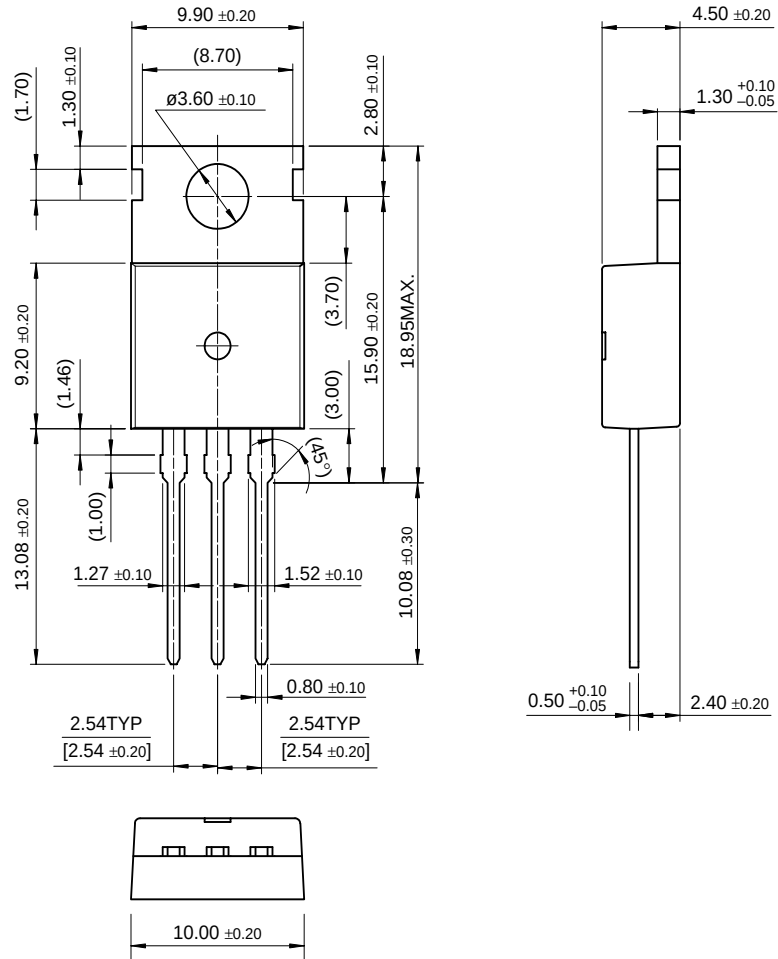


Figure 6. Power Derating

Package Dimensions

TO-220



Dimensions in Millimeters

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